

# Contents

## **Excitons in Semiconductors**

<i>Stephan W. Koch, Mackillo Kira</i> .....	1
1 Introduction .....	1
2 Absorption Spectroscopy .....	2
3 Photoluminescence .....	7
4 Terahertz Spectroscopy .....	10
5 Conclusions .....	16
References .....	17

## **Hot Excitons in ZnSe Quantum Wells**

<i>Hui Zhao, Heinz Kalt</i> .....	19
1 Introduction .....	19
2 Hot-Exciton Formation and Spectroscopy .....	20
3 Energy Relaxation of Hot Excitons .....	28
4 Hot-Exciton Transport .....	31
5 Conclusions .....	41
References .....	42

## **Probing Localized Excitons**

### **by Speckle Analysis of Resonant Light Scattering**

<i>Wolfgang Langbein, Gerrit Kocherscheidt, Roland Zimmermann</i> .....	47
1 Introduction .....	47
2 The Concepts of Speckle Analysis of Resonant Emission .....	47
3 Theoretical Description of Localized Excitons .....	51
4 Density Matrix Formulation of Exciton Scattering and Light Emission .....	53
5 Time-Resolved Speckle Analysis .....	58
6 Spectrally Resolved Speckle Analysis .....	64
7 Spectral Interferometry .....	66
8 Conclusion and Outlook .....	70
References .....	71

X      Contents

<b>Donor-Related Exciton Luminescence in Wide-Bandgap Semiconductors: Diamond, Zinc Oxide, and Gallium Nitride</b>	
<i>Rolf Sauer, Klaus Thonke</i> .....	73
1 Introduction .....	73
2 Diamond .....	73
3 Donors in ZnO and GaN: Determination of Ionization Energies from Photoluminescence (PL) Spectra .....	86
References .....	102
<b>Spectroscopy of Biexcitons and Trions in II-VI Quantum Dots</b>	
<i>Ulrike Woggon</i> .....	107
1 Introduction .....	107
2 Biexcitons in Nanocrystals .....	112
3 Biexcitons in Self-Organized Islands .....	120
4 Trion Properties in Quantum Dots .....	125
5 Dynamics of Single Excitons, Biexcitons, and Trions .....	126
6 Summary and Outlook .....	128
References .....	129
<b>Dynamics of Excitons and Exciton Complexes in Wide-Gap Semiconductors</b>	
<i>Jürgen Gutowski, Hans-Georg Breunig, Tobias Voss</i> .....	133
1 Introduction .....	133
2 Dynamics of Excitons, Trions and Biexcitons in Low-Dimensional Wide-Gap Semiconductors .....	134
3 Coherent Optics and Higher Coulomb Correlations in the Exciton Range of Wide-Gap Semiconductors .....	139
References .....	154
<b>Quantum Kinetics and Femtosecond Spectroscopy – The Discovery of Slowness</b>	
<i>Hartmut Haug</i> .....	159
1 Quantum Kinetic Regime .....	159
2 Non-equilibrium Many-Body Theory and Quantum Kinetics .....	162
3 Time-Dependent Screening of the Phonon and Coulomb Interactions .....	164
References .....	169
<b>Extreme Nonlinear Optics in Semiconductors</b>	
<i>Martin Wegener</i> .....	171
1 Extreme Nonlinear Optics of Two-Level Systems .....	171
2 Intraband Effects .....	180
3 Two Experimental Examples .....	182
4 Conclusions and Outlook .....	185
References .....	187

**Nonlinear Semiconductor Microcavities**

<i>Hyatt M. Gibbs</i> .....	189
1 Perturbative Regime: Optical Bistability .....	189
2 Nonperturbative Regime: Normal-Mode Coupling .....	190
3 Toward the Strong Coupling Regime .....	199
4 Conclusions .....	205
References .....	206

**All-Optical Control of Charge and Spin in GaAs:  
Densities and Currents**

<i>Martin J. Stevens, Ravi D.R. Bhat, Ali Najmaie, Henry M. van Driel, John E. Sipe, and Arthur L. Smirl</i> .....	209
1 Introduction .....	209
2 Theoretical Foundations of Quantum Interference .....	212
3 Symmetry Predictions: Charge Densities and Spin Densities .....	223
4 Experimental Coherent Control Techniques .....	225
5 Control of Charge and Spin Densities: Measurements .....	227
6 Symmetry Predictions: Charge Currents and Spin Currents .....	232
7 Electrical Detection of Spin-Polarized Charge Current .....	235
8 Optical Probing of Charge Current and Pure Spin Current .....	238
9 Summary .....	245
References .....	245

**Semiconductor Quantum Dots  
for Optoelectronic Applications**

<i>Tommy W. Berg, Jørn M. Hvam</i> .....	249
1 Introduction .....	249
2 Quantum Dot Fundamentals .....	249
3 Quantum Dot Semiconductor Optical Amplifiers .....	258
4 Conclusions .....	271
References .....	272

**GaInNAs: Fundamentals of a New Material System  
for Near-Infrared Optoelectronics**

<i>Michael Hetterich</i> .....	275
1 Introduction to GaInNAs-Based Laser Structures .....	275
2 Band Structure of GaAsN and GaInNAs .....	277
3 Boundary Conditions for the BAC Model Wave Function in GaInNAs-Based Heterostructures .....	279
4 BAC Model Calculation of Bound States in GaInNAs Quantum Wells .....	282
5 Influence of the Local N Environment on the BAC Hamiltonian Parameters .....	283
6 Conclusion .....	285
References .....	286

XII      Contents

<b>Nitride-Based Light Emitting Diodes and Laser Diodes: Optical Properties and Applications</b>	
<i>Martin Kuball</i> . . . . .	289
1 Introduction . . . . .	289
2 Historical Background . . . . .	290
3 Optical Properties of InN, GaN, AlN and Their Alloys . . . . .	292
4 Nitride-Based Light Emitting Diodes . . . . .	296
5 Nitride-Based Laser Diodes . . . . .	307
6 Conclusions . . . . .	314
References . . . . .	314
<b>Thermodynamics of Solar Cells</b>	
<i>Peter Würfel</i> . . . . .	321
1 Introduction . . . . .	321
2 Heat Engines Operating with Radiation . . . . .	321
3 Semiconductors . . . . .	327
4 Semiconductor Devices . . . . .	332
5 Conclusions . . . . .	340
References . . . . .	341
<b>Index</b> . . . . .	343